

Product Bulletin Document #: PB22209Z

Document #: PB22209Z Issue Date: 4 April 2018

Title of Change:	Datasheet update for NCV5700/NCD5700/01 series, DESAT charge current.		
Effective date:	4 April 2018		
Contact information:	Contact your local ON Semiconductor Sales Office or < Zarfaq.Jaffery@onsemi.com >		
Type of notification:	This Product Bulletin is for notification purposes only. ON Semiconductor will proceed with implementation of this change upon publication of this Product Bulletin.		
Change category:	☐ Wafer Fab Change ☐ Assembly Change ☐ Test Change ☐ Other		
Change Sub-Category(s): ☐ Manufacturing Site Change/Addition ☐ Material Change ☐ Product specific change ☐ Other:			
Sites Affected:	ON Semiconductor Sites: ON Carmona, Philippines External Foundry/Subcon Sites: None		
Description and Purpose: Based on additional test data, we are widening the limits for parameter lossAT-CHG to improve the yield. There is no change to the current product form, fit, or function. The new specification reflects a guard banded limit, enabling ON Semiconductor maintain its high quality standards. New Datasheet DESAT Threshold Voltage Voltage			
NCD5700DR2G NCD5701ADR2G NCD5701BDR2G NCD5701CDR2G NCV5700DR2G SNCV5700DR2G	Parts:		

TEM001797 Rev. O Page 1 of 1

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Appendix A: Changed Products D

Product	Customer Part Number
NCD5700DR2G	
NCD5701ADR2G	
NCD5701BDR2G	
NCD5701CDR2G	
NCV5700DR2G	
SNCV5700DR2G	